

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

# LA6581U — Fan Motor Driver BTL Driver Single-Phase Full-Wave

#### Overview

The LA6581U is a low-saturation BTL output linear driving motor driver for single-phase bipolar fan motors. It features quite, low power, high efficiency drive that suppresses reactive current. It is optimal for use in applications that require miniaturization and low noise, such as CPU cooling fan motors and 5 to 12V electronic game products.

#### **Functions**

- Single-phase full-wave linear drive with BTL output (gain resistance  $500\Omega$  to  $284k\Omega$ , 55dB): Suitable for the equipment requiring silent operation, such as game equipment, CPU cooler, etc. because of its freedom from switching noise.
- Low-voltage operation possible, with wide operable voltage range (3 to 16V)
- Low saturation output (Upper + lower saturation voltage :  $V_O$ sat (total) = 0.3V typ,  $I_O$  = 100mA) : High coil efficiency with low current drain. IC itself does not generate much heat.
- High impedance of Hall input pin
- FG output (rotation speed detection output : open collector output)
- Heat protection circuit: When the large current flows because of output short-circuit, raising the IC chip temperature above 180°C, the heat protection circuit suppresses the drive current, preventing IC burn and breakdown.
- Ultraminiature package (MSOP8J: 3.0mm×4.9mm×0.85mm typ): Small substrate while allowing larger blades.

#### **Specifications**

#### **Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Output voltage	V <sub>CC</sub> max		18	V
Output current	I <sub>OUT</sub> max	*1	0.36	Α
Output withstand voltage	V <sub>OUT</sub> max		18	V
FG output withstand	V <sub>FG</sub> max		18	V
FG output current	I <sub>FG</sub> max		5	mA

<sup>\*1:</sup> This specifies the starting current. Tj = 150°C max must not be exceeded.

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Parameter	Symbol	Conditions	Ratings	Unit
Allowable Power dissipation	Pd max	Mounted on a specified board *2	400	mW
Operating temperature	Topr		-30 to +95	°C
Storage temperature	Tstg		-55 to +150	°C

<sup>\*1:</sup> Specified board: 20.0mm × 10.1mm × 0.8mm, Paper phenol, wiring density 20%.

#### **Recommended Operating Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Supply voltage	Vcc		2.2 to 16	٧
Common-phase input voltage range	VICM		0.3 to V <sub>CC</sub> -1.5	V
of Hall input				

#### **Electrical Characteristics** at Ta = 25°C, V<sub>CC</sub> = 12.0V, unless especially specified.

Parameter	Cumph of	Conditions		Ratings		
	Symbol	Conditions	min	typ	max	Unit
Circuit current	Icc	$IN^- = 5.8V$ , $IN^+ = 6.0V$ , $RL = \infty$		14	19	mA
OUT output low voltage	VOL	I <sub>O</sub> = 100mA		0.1	0.2	V
OUT output high voltage	Voн	I <sub>O</sub> = 100mA		0.1	0.2	V
Hall bias voltage	V <sub>HB</sub>	I <sub>HB</sub> = 5mA	1.85	1.95	2.05	V
Hall amplifier gain	Vg		52	55	58	dB
Hall amplifier input current	VINR		-10	-2	10	μА
Input offset voltage	VOFST			3	6	mV
FG output low voltage	V <sub>FG</sub>	I <sub>FG</sub> = 3mA		0.2	0.3	V
FG output leakage current	l <sub>FGL</sub>	V <sub>FG</sub> = 7V			30	μА
Thermal protection circuit	Th	* Design guarantee	150	180	200	°C

 $<sup>\</sup>ensuremath{^*}$  Design guarantee : Design target. Measurement with a single unit not made.

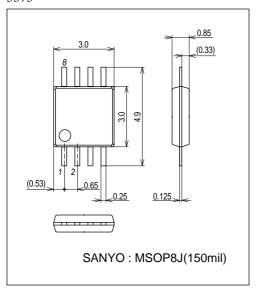
#### **Truth Table**

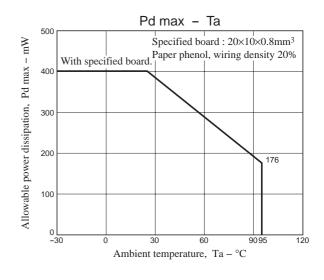
IN-	IN+	OUT1	OUT2	FG	Mode	
Н	L	Н	L	L	Duning pateting	
L	Н	L	Н	off	During rotation	
-	-	off	off	-	During overheat protection	

#### **Package Dimensions**

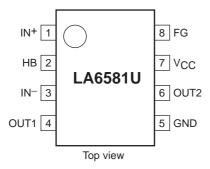
unit: mm (typ)

3373

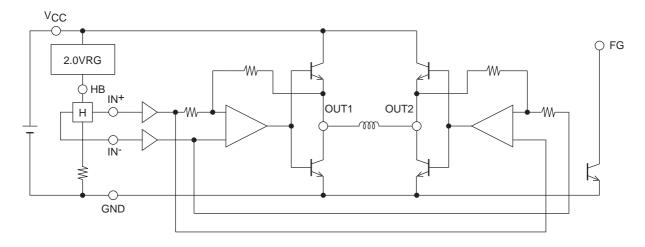




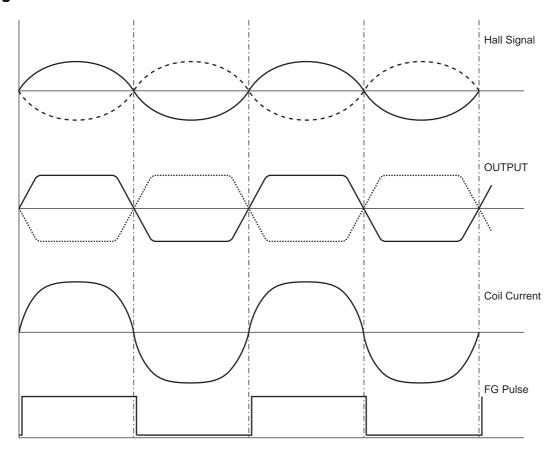
### **Pin Assignment**



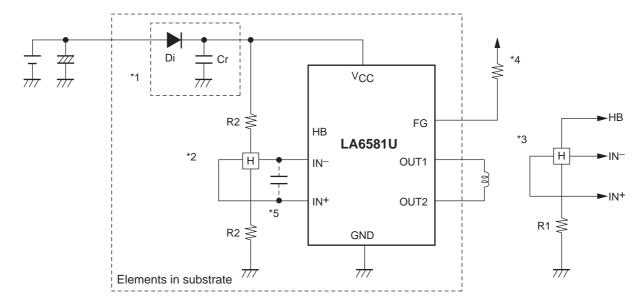
# **Block Diagram**



# **Timing Chart**



#### **Sample Application Circuit**



- \*1: When Di to prevent breakdown in case of reverse connection is used, it is necessary to insert a capacitor Cr to secure the regenerative current route. Similarly, Cr is necessary to enhance the reliability when there is no capacitor near the fan power line.
- \*2: To obtain Hall bias from  $V_{CC}$ , carry out  $1/2 \times V_{CC}$  bias as shown in the figure. Linear driving is made through voltage control of the coil by amplifying the Hall output. When the Hall element output is large, the startup performance and efficiency are improved. Adjustment of the Hall element can reduce the noise further.
- \*3: When the Hall bias is taken from the HB pin, constant-voltage bias is made with about 2.0V. Therefore, the Hall element can provide the output satisfactory in temperature characteristics. Adjustment of the Hall output amplitude is made with R1. (When  $V_{CC} = 12V$ , the step \*2 above proves advantageous for IC heat generation.)
- \*4: Keep this open when not used.
- \*5: When the wiring from the Hall output to IC Hall input is long, noise may be carried through the wiring. In this case, insert the capacitor as shown in the figure.
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